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Name (Print/Type)

Signature

RADE

REQUEST

## TINUED EXAMINATION (RCE) **TRANSMITTAL**

Subsection (b) of 35 U.S.C. § 132, effective on May 29, 2000, provides for continued examination of an utility or plant application filed on or after June 8, 1995. See The American Inventors Protection Act of 1999 (AIPA).

	<u> </u>	
Application Number	09/843,820	$\supset$ .1
Filing Date	April 30, 2001	#
First Named Inventor	Takahiko SATO	
Group Art Unit	2816	005
Examiner Name	A. Luu	Sunt
Attorney Docket Number	108397-00042	150

This is a Request for Continued Examination (RCE) under 37 C.F.R. § 1.114 of the above-identified application. 37 C.F.R. § 1.114 is effective on May 29, 2000. If the above-identified application was filed prior to May 29, 2000, applicant may wish to consider filing a continued prosecution application (CPA) under 37 C.F.R. § 1.53(d) (PTO/SB/29) instead of a RCE to be eligible for the patent term adjustment provisions of the AIPA. See Changes to application Examination and Provisions Application Practice, Fine Rule, 65 Fed. Reg. 50092 (Aug. 16, 2000); Interim Rule, 65 Fed. Reg. 14865 (Mar. 20, 2000), 1233 Off. Gaz. Pat. Office 47 (Apr. 11, 2000), which established RCE practice.

					ta:			
1.	S	ubmi	ssion required under 37 C.F.R. § 1.114		Realizable of the state of the	RE AL		
	a.	$\boxtimes$	Previously submitted		#' :	PE AUG AUG		
		i.		1.116 բ	previously filed on <u>July 10, 2</u>	600 ==		
		5	(Any unentered amendment(s) referred to above will be entered).		:	< ~ ~ ∺ I		
		ii.	Consider the arguments in the Appeal Brief or Reply	Brief p	reviously filed on <u></u>	T)		
		jii.	Other:			/EC 2002		
	b.	' <b>'</b>  ⊠	Enclosed					
		i.	□ Preliminary Amendment/Reply			280 1		
		ii.	Affidavit(s)/Declaration(s)			ಕ .		
		iii.	Information Disclosure Statement (IDS)		,			
	_	iv.	◯ Other:			(		
2.	N	1iscel	laneous			3		
	а.		Suspension of action on the above-identified application	is requ	ested under 37 C.F.R. § 1.1	03(c) for		
			a period of months. (Period of suspension shall n					
	b.		Other:		,			
3.	F	ees	The RCE fee under 37 C.F.R. § 1.17(e) is required by 37 C.F.R. § 1.1	14 when	the RCE is filed.			
	a.	Ø	The Director is hereby authorized to charge any deficient	y in the	e following fees or credit an	y overpayments		
	u.	<b>Z</b> .	to Deposit Account No. 01-2300, referencing 108397-000					
		i.	□ RCE fee required under 37 C.F.R. § 1.17(e)					
		ii.	Extension of time fee (37 C.F.R. §§ 1.136 and 1.17)			:		
		iii.	Other:					
	b.	$\boxtimes$	Check No. <u>345/46</u> in the amount of \$ <u>1140.00</u> .					
_								
			SIGNATURE OF APPLICANT, ATTORNE	, OR A	AGENT REQUIRED			
Nai	ne	(Print/	Type) Lynne D. Anderson	Registra	ation No. (Attorney/Agent)	46,412		
Sig	natur	e)	Linua Hadeison	Date	August 19, 2002			
CERTIFICATE OF MAILING OR TRANSMISSION								
I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner For Patents, Box RCE, Washington, DC 20231, or facsimile transmitted to the U.S. Patent and Trademark								
	Office on:							

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DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND Fees and Completed Forms to the following address: Assistant Commissioner for Patents, Box RCE, Washington, DC 20231.

Date

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## PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

SATO

Attorney Docket No: 108397=00042

Serial Number: 09/843,820

Group Art Unit: 2816

Filed: April 30, 2001

Examiner: A. Luu

SEMICONDUCTOR INTEGRATED CIRCUIT

PRELIMINARY AMENDMENT WITH FILING OF RCE

Commissioner for Patents Washington, D.C. 20231

August 19, 2002

Sir:

Prior to continued examination of the above-identified patent application, please amend the application as follows:

## IN THE CLAIMS:

Please add claims 10-13 as follows:

(New )The semiconductor integrated circuit according to claims 3, wherein said power-on resetting circuit and said voltage generator include transistors formed through a same manufacturing process.

- (New) The semiconductor integrated circuit according to claim 10, wherein 11. said transistors are nMOS transistors that have same threshold voltages.
- (New) The semiconductor integrated circuit according to claims 7, wherein 12. said power-on resetting circuit and said voltage generator include transistors formed through a same manufacturing process.
- (New) The semiconductor integrated circuit according to claim 12, wherein 13. said transistors are nMOS transistors that have same threshold voltages.--